Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	(deep near (channel or cavity or trench)) same (mono near crystal$4 near silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 19:29
L2	2421	(deep near (channel or cavity or trench)) same (silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 19:29
L3	49	2 and (wet near anisotropic$4 near etch$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 19:40
L4	2	216/57.ccls. and ((deep or shallow) near (trench or cavity or open$3))	US-PGPUB; USPAT	OR	OFF	2005/08/30 19:42
L5	81	216/57.ccls. and (silicon same etch$3)	US-PGPUB; USPAT	OR	OFF	2005/08/30 19:54
L6	8	(("6376291") or ("5429734") or ("4993143") or ("4685198")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 19:55
L8	4987	(epitaxi$4 near grow$3) same ($4crystal$4 near silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 20:32
L9	632	8 same (deep near trench or shallow near trench or cavity or open$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 20:40
L10	632	8 same ((deep near trench or shallow near trench or cavity or open$3) same silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 20:41
L11	468	10 and @pd<"20021204"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 20:41

S1	116	(channel or cavity or trench) same (mono near crystal$4 near silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/30 19:26
S2	13	S1 same anisotropic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:37
S3	34569	((channel or cavity or trench) same silicon) same etch$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:39
S4	13755	S3 and anisotrop$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:40
S5	11814	S4 and mask$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:40
S6	6979	S3 same anisotrop$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:41
S7	3392	S6 same mask$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:41
S8	760	S7 same plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:41
S9	443	S8 and @pd<"20021204"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/29 21:42

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	14257	(potassium near hydroxide or "KOH" or "TMAH") same (ammonium near hydroxide or "NH.sub.4 OH")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/31 19:43
L2	691	1 same (silicon same etch$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/31 19:43
L3	305	2 and @pd<"20021204"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/31 19:45
L4	148	3 and (trench or cavity)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/31 19:46